

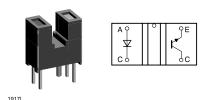
Transmissive Optical Sensor with Phototransistor Output

Description

The TCST1030 and TCST1030L are transmissive sensors that include an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light. TCST1030L is the long lead version.

Features

- Package type: Leaded
- Detector type: Phototransistor
- Dimensions:
- L 8.3 mm x W 4.7 mm x H 8.15 mm
- Gap: 3 mm
- Aperture: none
- Typical output current under test: I_C = 2.4 mA
- Daylight blocking filter
- Emitter wavelength 950 nm
- Lead (Pb)-free soldering released
- Lead (Pb)-free component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC



Applications

- Optical switch
- Shaft encoder
- Detection of opaque material such as paper
- Detection of magnetic tapes

Order Instructions

| Part Number | Remarks | Minimum Order Quantity |
|-------------|--------------------|------------------------|
| TCST1030 | 3.4 mm lead length | 5200 pcs, 65 pcs/tube |
| TCST1030L | 16 mm lead length | 2600 pcs, 65 pcs/tube |

Absolute Maximum Ratings

 T_{amb} = 25 °C, unless otherwise specified

Coupler

| Parameter | Test condition | Symbol | Value | Unit |
|-----------------------------|---|------------------|---------------|------|
| Total power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | P _{tot} | 250 | mW |
| Operation temperature range | | T _{amb} | - 25 to + 85 | °C |
| Storage temperature range | | T _{stg} | - 25 to + 100 | °C |
| Soldering temperature | 1.6 mm from case, $t \leq 10 \mbox{ s}$ | T _{sd} | 260 | °C |

Vishay Semiconductors



Input (Emitter)

| Parameter | Test condition | Symbol | Value | Unit |
|-----------------------|------------------------------|------------------|-------|------|
| Reverse voltage | | V _R | 6 | V |
| Forward current | | ١ _F | 60 | mA |
| Forward surge current | $t_p \le 10 \ \mu s$ | I _{FSM} | 3 | A |
| Power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | P _V | 100 | mW |
| Junction temperature | | Tj | 100 | °C |

Output (Detector)

| Parameter | Test condition | Symbol | Value | Unit |
|---------------------------|------------------------------|------------------|-------|------|
| Collector emitter voltage | | V _{CEO} | 70 | V |
| Emitter collector voltage | | V _{ECO} | 7 | V |
| Collector current | | Ι _C | 100 | mA |
| Power dissipation | $T_{amb} \le 25 \ ^{\circ}C$ | P _V | 150 | mW |
| Junction temperature | | Тj | 100 | °C |

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Coupler

| Parameter | Test condition | Symbol | Min | Тур. | Max | Unit |
|--------------------------------------|---|--------------------|-----|------|-----|------|
| Collector current | $V_{CE} = 5 \text{ V}, I_F = 10 \text{ mA}$ | ۱ _C | 1.2 | 2.4 | | mA |
| Collector emitter saturation voltage | I _F = 10 mA, I _C = 1 mA | V _{CEsat} | | | 0.8 | V |

Input (Emitter)

| Parameter | Test condition | Symbol | Min | Тур. | Max | Unit |
|----------------------|-------------------------------|----------------|-----|------|-----|------|
| Forward voltage | I _F = 60 mA | V _F | | 1.25 | 1.5 | V |
| Junction capacitance | V _R = 0, f = 1 MHz | Cj | | 50 | | pF |

Output (Detector)

| Parameter | Test condition | Symbol | Min | Тур. | Max | Unit |
|---------------------------|---|------------------|-----|------|-----|------|
| Collector emitter voltage | I _C = 1 mA | V _{CEO} | 70 | | | V |
| Emitter collector voltage | I _E = 10 μA | V _{ECO} | 7 | | | V |
| Collector dark current | $V_{CE} = 25 \text{ V}, \text{ I}_{F} = 0, \text{ E} = 0$ | I _{CEO} | | 10 | 100 | nA |

Switching Characteristics

| Parameter | Test condition | Symbol | Min | Тур. | Max | Unit |
|---------------|--|------------------|-----|------|-----|------|
| Turn-on time | $I_C = 1 \text{ mA}, V_{CE} = 5 \text{ V},$ $R_L = 100 \Omega \text{ (see figure 1)}$ | t _{on} | | 15.0 | | μs |
| Turn-off time | $I_{C} = 1 \text{ mA}, V_{CE} = 5 \text{ V},$ $R_{L} = 100 \Omega \text{ (see figure 1)}$ | f _{off} | | 10.0 | | μs |



TCST1030(L) Vishay Semiconductors

+ 5 V 0 I_C = 1 mA; adjusted by I_F $R_{G} = 50 \ \Omega$ $\frac{t_p}{T} = 0.01$ \mathbb{V} t_p = 50 μs 0 Channel I Oscilloscope -0 Channel II $R_L \geq ~1~M\Omega$ $C_L \le 20 \text{ pF}$ 50 Ω $100\,\Omega$ 20223

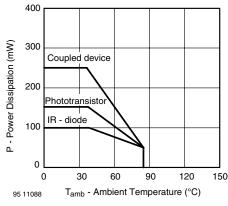
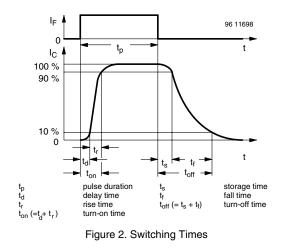


Figure 1. Test Circuit for ton and toff



Typical Characteristics

 $T_{amb} = 25$ °C, unless otherwise specified

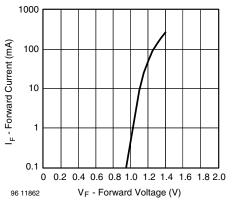
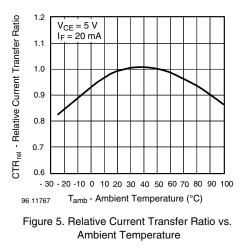


Figure 4. Forward Current vs. Forward Voltage

Figure 3. Power Dissipation Limit vs. Ambient Temperature



Vishay Semiconductors



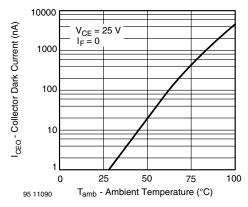


Figure 6. Collector Dark Current vs. Ambient Temperature

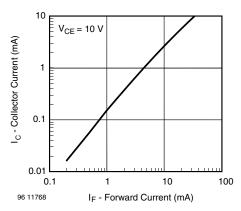


Figure 7. Collector Current vs. Forward Current

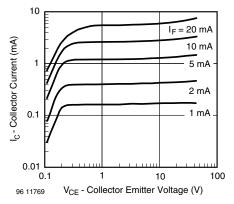


Figure 8. Collector Current vs. Collector Emitter Voltage

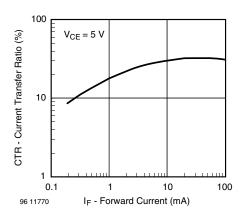


Figure 9. Current Transfer Ratio vs. Forward Current

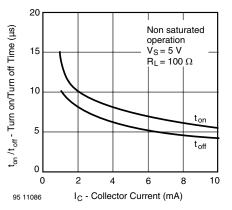


Figure 10. Turn on/off Time vs. Collector Current

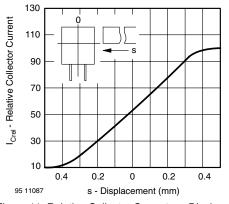
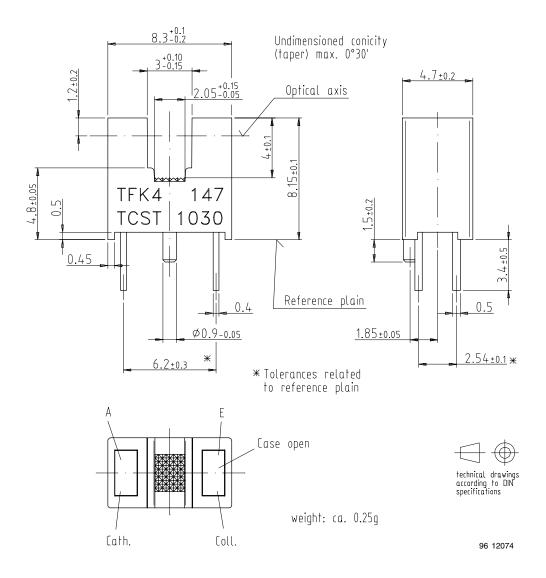


Figure 11. Relative Collector Current vs. Displacement



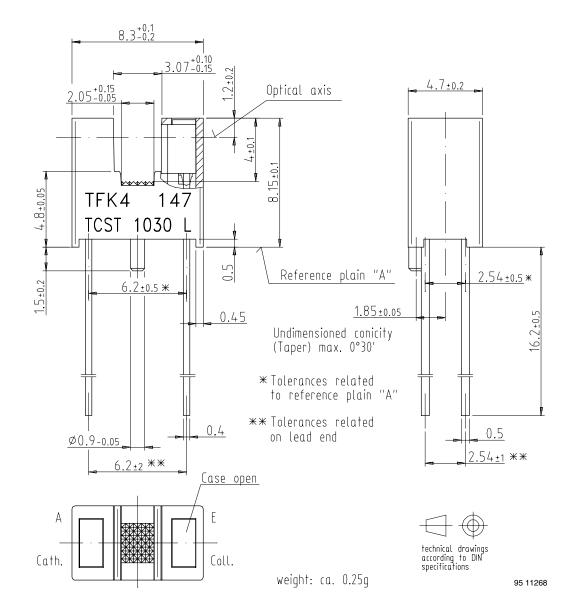


Package Dimensions in mm



Vishay Semiconductors

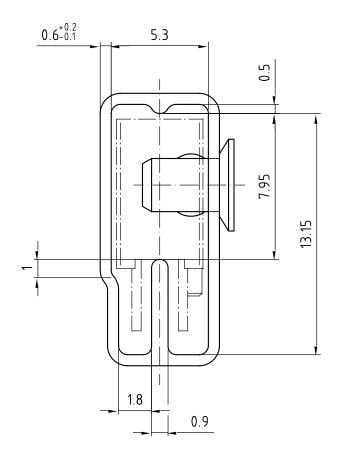






TCST1030(L) Vishay Semiconductors

Tube Dimensions in mm



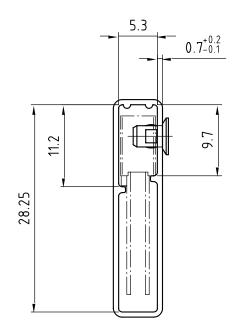
With stopper pins Tolerance: ±0.5mm Length: 575±1mm

All dimensions in mm

Drawing-No.: 9.700-5140.01-4 Issue: 1; 25.02.00 20253

Vishay Semiconductors





With stopper pins Tolerance: ±0.5mm Length: 575±1mm All dimensions in mm

Drawing-No.: 9.700-5205.01-4 Issue: 1; 25.02.00 20254



Vishay Semiconductors

Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany



Vishay

Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.